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Abstract

We report on an experiment that demonstrates the frequency up-conversion of telecommunication wavelength single-photon-level pulses to be resonant with a Pr\textsuperscript{3+}:Y\textsubscript{2}SiO\textsubscript{5} crystal. We convert the telecom photons at 1570 nm to 606 nm using a periodically-poled potassium titanyl phosphate nonlinear waveguide. The maximum device efficiency (which includes all optical loss) is inferred to be $\eta_{\text{dev}}^{\text{max}} = 22 \pm 1\%$ (internal efficiency $\eta_{\text{int}} = 75 \pm 8\%$) with a signal to noise ratio exceeding 1 for single-photon-level pulses with durations of up to 560 ns. The converted light is then stored in the crystal using the atomic frequency comb scheme with storage and retrieval efficiencies exceeding $\eta_{\text{AFC}} = 20\%$ for predetermined storage times of up to 5 $\mu$s. The retrieved light is time delayed from the noisy conversion process allowing us to measure a signal to noise ratio exceeding 100 with telecom single-photon-level inputs. These results represent the first demonstration of single-photon-level optical storage interfaced with frequency up-conversion.

Keywords: quantum information, quantum memory, nonlinear waveguides

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1. Introduction

Quantum information technology relies on quantum light-matter interfaces, in particular, quantum memories for light [1]. Such a device would allow for the synchronization of probabilistic events, for example generation of photon pairs from independent sources [2]. This is an important resource in the context of linear-optical quantum computation [3, 4] and long distance quantum communication with quantum repeaters [5, 6]. This architecture promises to overcome the unavoidable problem of the limited distance due to loss of fiber-based quantum communication schemes [7].

Quantum photonic memories utilize atomic systems, as light can be absorbed on the optical transitions and stored as atomic excitations for durations limited by the coherence time. Moreover, if this coherence can be transferred to the ground state as a spin-wave, even longer storage times are possible. Many atomic systems have been investigated as quantum memories for light, including single atoms [8], warm atomic vapours [9, 10], laser cooled atomic ensembles [11–14], room temperature bulk diamond [15], nitrogen-vacancy centers in diamond [16], hydrogen molecules [17], metastable helium [18] and rare earth ion doped solids at cryogenic temperatures [19–33].

Of great interest to long distance quantum communication is the implementation of a quantum memory for telecommunication light (1550 nm). It is well known that telecom C-band optical fibers have the least loss (0.2 dB km$^{-1}$), so a telecom optical memory would integrate directly with fiber-optical networks and quantum repeater architectures. The obvious strategy for a telecom memory is the use of an atomic system which can directly absorb telecom light, for example erbium-doped solids which have a transition around 1530 nm. Unfortunately, for this material (at a few Kelvin) the degree of spin polarization is low and thus limits the overall efficiency for memories based on spectral tailoring of the inhomogeneously broadened line. Two memory protocols were investigated in Er$^{3+}$:Y$_2$SiO$_5$ with light below the single-photon-level [21, 25], the atomic frequency comb (AFC) [34] and controlled reversible inhomogenous broadening (CRIB) [35, 36] protocols, with sub-percent total efficiencies at sub-microsecond storage times. Further to these experiments, non-classical telecom light storage in an erbium-doped optical fiber using the AFC protocol was recently demonstrated [33], with efficiencies of about 1% at a storage time of 5 ns.

Other protocols that do not require spectral tailoring have been proposed recently [37, 38]. In particular, a memory efficiency of 40% was observed with strong input pulses and Er$^{3+}$: Y$_2$SiO$_5$ [30] using the revival of silenced echo (ROSE) protocol. However, since these protocols are based on strong rephasing pulses at the same frequency as the retrieved echo, the ability to use them as a quantum memory remains technically challenging. In a different system, the ROSE protocol was limited to input weak coherent states of 14 photons per pulse, due to the noise created by the strong control pulses [27].

An alternate option with a telecom transition are rubidium-based systems, where the use of nonlinear processes, such as four-wave-mixing (FWM), can convert the frequency of the input telecom photons to be resonant with the rubidium based memory and has recently been demonstrated in [39] albeit with the use of strong input light and a very low efficiency.

Another strategy implemented in [31] is to teleport the quantum state of a telecom photon into the memory using entanglement between a telecom photon and a collective atomic excitation [23, 24]. This method benefits in that any memory can be used, provided one can herald a photon pair where one of the pair is resonant with the memory and the other at telecom
frequency. Then, the quantum state of an additional telecom photon can be teleported into the memory by performing a Bell-state measurement between said photon and the generated telecom photon.

Yet another alternative is to use quantum frequency conversion via a nonlinear process as an interface between a memory and telecom wavelengths. So far, this has only been demonstrated for emissive type memories based on the Duan–Lukin–Cirac–Zoller protocol [6]. The signal Stokes photon has been down- and then up-converted to and from a telecommunication wavelength via FWM in an additional cold rubidium ensemble [13] and the heralded anti-Stokes photon has been frequency down-converted to telecom light using a nonlinear waveguide [40]. For both cases, the non-classicality between Stokes and anti-Stokes was preserved.

Here, we report on the first demonstration of interfacing single-photon-level telecom pulses to an absorptive memory using frequency conversion. The material we use as the memory is Pr$^{3+}$:Y$_2$SiO$_5$ with the optical transition at 606 nm, a particularly good candidate for a quantum optical memory. Included in the recent experiments with this system are the 56% storage of light using the AFC protocol [28], 69% quantum storage of weak coherent states using the CRIB protocol [20], light storage for up to one minute using electromagnetically induced transparency [29], quantum storage of polarization qubits [26], storage of quantum light [41] and spin-wave storage [22, 42]. To interface this material with the telecom C-band, we use frequency up-conversion in a nonlinear waveguide to convert weak light at 1570 nm to 606 nm. Such a technique has been employed as an efficient way to detect broadband single-photon-level telecom light [43–48] and conversion of nonclassical light [49–52]. However, in order to match our optical memory bandwidth, long photons (>100 ns) should be converted, which increases the requirements for noise suppression. For the maximum pump power available in our experiment, the device efficiency of the converter (inclusive of all optical loss) is measured to be 21 ± 1%. Using the AFC protocol we can store the up-converted photon for times up to $\tau_{\text{AFC}} = 10 \mu$s with a maximum overall efficiency (conversion efficiency, memory efficiency and all optical loss) of $\eta_{\text{tot}} = 1.9 \pm 0.2\%$ at $\tau_{\text{AFC}} = 1.6 \mu$s storage time, currently outperforming previous realizations of absorptive telecom optical memories at the single-photon-level.

2. Experimental set up

Figure 1 shows a simplified experimental set-up. There are two main parts to the device: the frequency converter (FC) and the AFC solid-state optical memory, of which we first describe the former.

2.1. FC

Our FC is based on a frequency up-conversion process in a 2.6 cm long periodically-poled potassium titanyl phosphate (PPKTP) nonlinear waveguide (AdvR). With pump photons at 987 nm and signal photons at 1570 nm coupled to the waveguide, a nonlinear process frequency up-converts the telecom photons to 606 nm when both energy and momentum are conserved [53]. The waveguide has a quasi-phase matched bandwidth over which efficient frequency conversion occurs, the bandwidth depending on the poling period [53].
For the pump, we use a Toptica external cavity diode laser (ECDL) with a tapered amplifier providing about 1.2 W of 987 nm, which is coupled to a single mode fiber resulting in a maximum of 600 mW at the input of the FC. We note that some of this light is also used to generate the 606 nm beam for preparation of the memory (see subsection 2.2). For the signal, we use again a Toptica ECDL but with a Keopsys erbium-doped fiber amplifier to have around 1 W of 1570 nm. A 95:5 fiber beam splitter is used, the weaker port used for the FC, the stronger port used to create light for the memory preparation (see subsection2.2).

To couple to the nonlinear waveguide, we use a lens (Thorlabs, \( f = 11 \text{ mm}, \ NA = 0.25 \)) mounted on a three-axis translation stage. The transmission in the waveguide (including waveguide coupling and losses) of the pump and signal modes are measured to be 36% and 55%, respectively, both cases being limited by mode-matching. Both in-coupled optical modes pass through acousto-optic modulators (AOM—AA optoelectronic). For the signal mode, there is a double-pass configuration which ensures the frequency of the up-converted photons exactly matches that of the memory (see subsection 2.2). Also in the signal mode are OD filters to reduce the light to the single-photon-level. The AOM in the pump mode is operated in single pass and acts as a gate, the zeroth order mode being coupled to the FC such that when the AOM is activated, about 75% of the pump power is steered away from the FC. Moreover, when the
AOM is activated the mode shape of the zeroth order is distorted, further reducing the coupled power to the waveguide. With this gating system, we are able to reduce the up-converted signal by a factor exceeding 10. This gating becomes useful for detection of the light retrieved from the crystal.

The up-converted mode is subject to frequency filtering. We use a diffraction grating (Thorlabs, GR13-1205) to remove from the output mode the pump light, the signal light that is not converted and the up-converted pump light (493.5 nm). A more problematic source of noise is pump induced Raman scattering and spurious spontaneous parametric down-conversion [47]. This noise can include the input frequency and will thus be up-converted as a broadband noise about the target frequency, the bandwidth given by the quasi-phase matching condition. To reduce this effect, we employ an etalon (light machinery) with finesse 6 and linewidth 10 GHz. The total transmission from the output of the waveguide to after the last frequency filtering component is 71%.

Finally, the output mode is coupled to a telecommunication wavelength fiber which is slightly multimode for 606 nm but allows for an efficient coupling of 75%. The combination of this fiber with the grating gives an estimated filtering bandwidth of 80 GHz. The light is then either coupled to a single photon detector (SPD) for direct analysis of the FC, or coupled to the crystal for storage. The total transmission from the output of the waveguide to after the fiber is then 53%.

2.2. Storage device

Our device is based on the AFC protocol [34]. This protocol is well suited for inhomogeneously broadened and spectral holeburning media. An incoming photon is collectively absorbed by the medium creating an atomic coherence which dephases due to the inhomogeneity. However, if the absorption line is tailored into a periodic structure with a well defined frequency spacing of \( \Delta \) (referred to as a comb), the atomic coherence will rephase at a time \( \tau_{\text{AFC}} = 2\pi/\Delta \) resulting in photon-echo like emission. For a given storage time and optical depth, there is an optimal finesse, \( F \), that maximizes the efficiency, where the finesse is defined as the ratio of the comb teeth spacing \( \Delta \) to the comb tooth width \( \gamma \). Additionally, there is a lineshape of the teeth of the comb that maximizes the efficiency [54].

We note that the storage time here is predetermined and therefore the light can not be recalled on-demand. However, the full AFC scheme is directly applicable in our system [22, 42], where the optical excitation can be transferred to the ground state to be stored as a long-lived spin-wave and then recalled on-demand. Such on-demand memories become useful as synchronizing devices, e.g. in the context of quantum repeater technology [5]. In addition, note that the AFC scheme alone can be useful even with a fixed storage time, e.g. if combined with temporal and spectral multiplexing with feed-forward control and read-out in the spectral domain, as described and demonstrated in [32]. Our system is compatible with this technique.

As the memory medium, we use a 5 mm long Pr\(^{3+}\):Y\(_2\)SiO\(_5\) crystal with 0.05% doping leading to an absorption coefficient of 23 cm\(^{-1}\) with light polarized along the D\(_2\) crystal axis. For light polarized along the D\(_1\) axis, the absorption coefficient is reduced greatly [55]. The transition of interest is at 606 nm which connects the first sublevels of the \(^3\)H\(_2\) ground and the \(^1\)D\(_2\) excited manifolds. To cool this crystal to cryogenic temperatures we use a Montana instruments cryostation mounted on a different table to that of the laser source and conversion set-up. The 606 nm laser source used for preparation is based on sum-frequency-generation of
1570 nm and 987 nm in a second PPKTP waveguide. The light is derived from the same lasers described in subsection 2.1. The frequency of the 987 nm light is locked via Pound–Drever–Hall to a cavity using 606 nm light generated in a different waveguide set-up [42]. A single-mode fiber brings about 2 mW of light to the cryostation for the preparation mode.

We use a double pass AOM to first create a 12 MHz wide transparency window (referred to as ‘pit’) via spectral holeburning the atoms to other hyperfine levels of Pr³⁺:Y₂SiO₅. The population lifetime of the ground state is around ~100 s [56] with an optical excited state lifetime of 164 µs [57], making spin polarization and thus spectral holeburning simple. We burn ions back into the pit by sweeping the laser 4 MHz centered at +30 MHz with respect to the pit centre. This populates the ±1/2_g and ±3/2_g ground states within the pit (see inset of figure 1 for level diagram), and by then emptying again the ±3/2_g ground state via optical pumping, we are left with a 4 MHz wide single class of ions within the ±1/2_g ground state [58, 59]. Within this single class, spectral holes at regular Δ intervals are burnt resulting in a 4 MHz wide AFC resonant with the ±1/2_g − ±3/2_e transition (see inset of figure 1). The burnt ions are then placed into the ±3/2_g and ±5/2_g ground states. The total preparation time for the memory is around 200 ms.

Finally, the preparation mode is sent at an angle of about 4° with respect to the input mode, overlapping only on the memory. This allows to spatially filter the strong preparation light away from the single photon detection mode.

Important for the overall efficiency of the device is the loss the input mode experiences from being out-coupled from the fiber, passing through the memory and being fiber coupled again to the detector. To reduce the loss we use a multimode fiber for coupling to the detector. The total transmission from after the telecom fiber to after the multimode fiber is 66%.

2.3. Detection

Further to spatially filtering the preparation light from the detection, a mechanical shutter is used to physically block the SPD from leaked scattered light of the preparation. The SPD used is from PicoQuant (Tau SPAD-20) with a measured 10 Hz dark count rate and a specified 60% detection efficiency at 606 nm. When coupling light after the memory to the detector we use a multimode fiber. When testing only the FC, the telecom fiber is used to couple to the SPD. Finally, as an extra filtering stage, we use a bandpass filter of 10 nm width around 605 nm which is placed directly before the fiber coupler in all detection cases.

With a time to digital converter (TDC—Signadyne), we perform start-stop measurements. We send 1.2 × 10⁶ pulses at a rate of around 50 kHz. When the memory is in place, these pulses are sent as 200 lots of 6000, where the 6000 pulses are sent within 150 ms. For each lot of 6000 pulses, a new AFC is prepared.

For all results shown, we note that the dark counts of the detector are not subtracted.

3. Frequency conversion of single-photon-level light

We first characterize the frequency conversion of single-photon-level 1570 nm light independent of the memory. An important value of the FC is the device efficiency η_dev, which we define as the ratio of the number of 606 nm photons at the detector to the number of 1570 nm photons at the input lens of the device. We measure this as a function of pump power after the waveguide, P_p, in figure 2(a). For this data we use an input of μ_in = 1, which refers to the
average number of photons per pulse. The pulse duration is 140 ns and we correct only for the SPD efficiency (60%). The data are fitted with the following equation

\[ \eta = \eta_{\text{dev}} \sin^2 \left( L \sqrt{P_p \eta_{\text{in}}} \right), \]  

(1)

where \( L \) is the length of the waveguide and \( \eta_{\text{in}} \) is the normalized efficiency. This equation can be obtained by treating the pump light classically and having vacuum at the converted photon frequency at the input of the device. The maximum measured device efficiency is 21 ± 1\% for \( P_p = 252 \text{ mW} \). Extracting from the fit, the maximum device efficiency is inferred to be \( \eta_{\text{dev}}^{\text{max}} = 22 \pm 1\% \) for \( P_{\text{max}} = 360 \text{ mW} \) and a normalized efficiency of \( \eta_{\text{in}} = 100 \pm 10\% / \text{W cm}^2 \).

Correcting for all known losses, e.g. fiber coupling (75\%) and propagation losses (71\%), we can infer the external efficiency, i.e. the efficiency directly outside of the waveguide, to be \( \eta_{\text{ext}} = 41 \pm 4\% \). Taking into account the coupling of the 1570 nm to the waveguide (55\%), we infer the internal efficiency to be \( \eta_{\text{int}} = 75 \pm 8\% \). That is, 75\% of what telecom light is coupled into the waveguide is converted.

In figure 2(a) we show also the dependence of the noise as a function of pump power after the waveguide for \( \mu_{\text{in}} = 1 \). Here we fit with a quadratic function of the form \( \alpha P_p^2 + \beta P_p + \text{DC} \) where \( \alpha / \beta \) are free parameters and DC is the dark count of the detector. This is the expected behaviour of this system, the noise being a result of two processes: (i) the pump inducing photons at the input frequency via weakly phase-matched down-conversion due to non-perfect poling [60] which are then up-converted and (ii) spontaneous Raman scattering of the pump [47]. The noise due to down-conversion can be avoided simply if the pump frequency is lower than that of the input. However, to interface light near the telecom C-band (1.5–1.6 \( \mu \text{m} \)) to a \( \text{Pr}^3+:\text{Y}_2\text{SiO}_5 \) based memory (606 nm), the pump (1016–975 nm) will always be more energetic.
than the input. Therefore, for our application, this noise via SPDC is unavoidable, unless a cascaded conversion scheme is used [48].

Shown in figure 2(b) is the signal to noise ratio versus pump power after the waveguide, where SNR = \( \frac{S - N}{N} \) with S being the total number number of counts (including noise) and N being the noise counts. At \( P_{\text{max}} \), the signal to noise ratio still exceeds 1. For pump powers larger than this, we enter the regime where the up-converted photons are being down-converted again, leading to signal to noise ratios below 1.

4. Storing up-converted single-photon-level telecom light

Having characterized the conversion, we now couple the light to the crystal, with figure 3 showing the results. At the input of the FC, photon numbers ranging from 0.05 to 2 photons per 140 ns pulse were used and the signal to noise ratio was measured for three cases: the FC alone, the photons passing through a 12 MHz transparency window created in the memory crystal and finally the stored and retrieved photons from the memory. For the second case, the light is polarized along the D1 crystal axis, whereas for the third case the polarization is along the D2 axis. The characteristic value we choose to compare for the three cases is the minimum input photon number required to achieve a signal to noise ratio of 1, the so-called \( \mu_1 \). The \( \mu_1 \) is
extracted from a linear fit of the data, where the fit is forced to pass through zero. For all measurements in this section, the pump power is set to 144 mW leading to an FC device efficiency of 15 ± 1%.

For the case of the FC alone, where the photons are measured after coupling to the telecom fiber, we measure $\mu_1 = 0.37 \pm 0.02$ photons. The integration window taken is 400 ns which includes the entire pulse. A 2.36 $\mu$s noise window is taken in the same trace, located 7.48 $\mu$s after the input pulse, with the counts normalized to 400 ns.

We then out-couple the light and steer it toward a 12 MHz transparency window tailored in the inhomogenous absorption line of the Pr$^{3+}$:Y$_2$SiO$_5$ crystal and we measure $\mu_1 = 0.23 \pm 0.004$ photons. The signal and noise detection windows here are the same as the previous case. An improvement in the $\mu_1$ is seen, this is due to the absorption of the noise by inhomogenous linewidth of the sample. The etalon placed after the converter (see figure 1) has a linewidth of around 10 GHz resulting in noise with this bandwidth. With the noise polarized along the D$_1$ axis we measure a reduction of 33% which is consistent with an absorbing line of width 6–12 GHz.

Finally, for the case of the stored light we measured $\mu_1 = 1.38 \pm 0.03 \times 10^{-3}$ photons, about a factor of 270 improvement compared to the FC only case. The memory efficiency is measured to be $\eta_{\text{AFc}} = 19.8 \pm 0.1\%$. One key feature here is that the echo signal is delayed by a known time of $\tau_{\text{AFc}} = 1.6 \mu$s, which allows us to disable the 987 nm pump of the FC before the echo is re-emitted from the sample. This can be seen clearly in the inset of figure 3 where at a time of about 1 $\mu$s the pump is disabled resulting in a dramatic drop of noise in the echo temporal window. The pump is disabled for a total time of 5 $\mu$s, and to measure the noise we take a measurement with the input telecom photons physically blocked at the input of the converter and integrate over the entire 5 $\mu$s that the pump is off. The signal integration window remains the same as the previous cases.

Due to the narrowband nature of the memory (about 4 MHz relative to the >5 GHz noise), the memory itself acts as a filter of the noise storing only a fraction of it. This, in combination with the fact that the pump is gated, thus allows for a two orders of magnitude reduction in the $\mu_1$ for the echo.

From the echo and the input photon number we can extract the total efficiency of our device (including frequency conversion, all optical loss and storage efficiency), which we measure to be $\eta_{\text{tot}} = 1.55 \pm 0.02\%$. From the device efficiency seen in section 3 (∼15% at 144 mW pump power), an additional 66% transmission loss from memory input to the SPD and the AFC efficiency (∼20%), we have quantitative agreement between using strong and single-photon-level light.

We measure also the echo efficiency together with the signal to noise ratio as a function of storage time from $\tau_{\text{AFc}} = 1.6 \mu$s up to $\tau_{\text{AFc}} = 10 \mu$s, shown in figure 4. For this data, we use pulses of an increased duration of 560 ns while keeping the AFC bandwidth constant. We increase also the integration window to 1.2 $\mu$s. The resulting $\mu_1$ for FC only is $\mu_1 = 0.92 \pm 0.03$. With precise control of the peak width $\gamma$ and separation $\Delta$ (and thus the AFC finesse), we can keep the efficiency of the memory (and thus the total efficiency) quite constant for storage times up to $\tau_{\text{AFc}} = 5 \mu$s. The efficiency of the echo at a storage time of $\tau_{\text{AFc}} = 1.6 \mu$s sees an increase to $27.4 \pm 0.4\%$ due to the bandwidth of the pulses being narrower [61]. The total efficiency for this storage time is $1.9 \pm 0.2\%$. At $\tau_{\text{AFc}} = 5 \mu$s where the echo efficiency is $\eta_{\text{AFc}} = 19.1 \pm 0.2\%$, the $\mu_1$ is $8.6 \pm 0.5 \times 10^{-3}$ and the overall improvement seen is reduced to about 107 (compared to 270 for the previous case). This reduction is partly
due to the increase in integration window (and hence noise) and because the pump gating was not as effective for this particular data set.

5. Discussion

Our conversion and storage device currently outperforms previous realizations of absorptive telecom memories at the single-photon-level [21, 25]. However the storage time and more so the efficiency demonstrated here needs significant improvement to be useful within quantum information processing technology. Despite this low efficiency operation, we have demonstrated that narrowband quantum memories can efficiently and effectively filter narrowband signals from broadband noise. Since only a fraction of the noise is stored in the memory, a drastic decrease in $\mu_1$ is achieved. Such filtering effects have been witnessed previously with AFC quantum memories in different contexts [41, 62]. Rather than a telecom memory, our device can be viewed as a noiseless converter of telecom photons to the visible.

We now discuss strategies to improve the efficiency. There are three contributions to the total efficiency $\eta_{\text{tot}}$: the device efficiency $\eta_{\text{dev}}$ of the converter, the propagation loss $\eta_{\text{trans}}$ from converter to memory, and the AFC memory efficiency $\eta_{\text{AFC}}$. Below we discuss ways to improve these.

The device efficiency has three contributions, the internal efficiency, the signal coupling to the waveguide, and the transmission through filtering stages. Regarding the internal efficiency, we operated at a pump power much below $P_{\text{max}}$ for the storage experiments due to limited available power. Therefore the total efficiency can be increased by simply increasing the pump power. Of course, an increased pump power necessarily results in an increased noise, however
our memory can tolerate noise due to its effect of narrowband filtering. Note that the maximum internal efficiency is already quite high at 75%.

The coupling of the signal to the waveguide is only 55% which could be increased with better mode-matching or fiber-pigtailing. Alternatively, a cavity-enhanced scheme with bulk crystal can be used [45, 52], where high internal efficiencies have also been observed.

The transmission of the filtering stage of the FC is 53% most of which is due to the diffraction grating (71%) and fiber coupling (75%). This could be improved by using a volume-Bragg grating.

A major source of loss between the FC and the AFC is the depolarization of the light in the telecom fiber (slightly multimode at 606 nm). We use two quarter-wave plates surrounding a half-wave plate to control the polarization giving around 80% transmission through a polarizing beam splitter placed before the memory.

For the AFC efficiency, there are realizations that operated with higher efficiencies using Pr$^{3+}$:Y$_2$SiO$_5$. For example, using a cavity enhanced scheme as in [28] an efficiency of 56% was realized. Using an alternative memory scheme, 69% efficiency was possible [20].

We demonstrated that our device can store pulses of 560 ns duration which is compatible with the input pulses used for the full AFC memory demonstrated in [22, 42]. Therefore, in principle, a spin-wave AFC memory for up-converted telecom photons is possible. Using strong control pulses to transfer the optical excitation to a spin-wave, the storage time can be increased to that of the hyperfine inhomogeneity (about 25 $\mu$s for Pr$^{3+}$:Y$_2$SiO$_5$ [22, 42]) and recalled on-demand. Further increasing of the storage time can be obtained via application of magnetic fields and dynamical decoupling techniques [29, 63]. We note that a spin-wave AFC memory is not possible in previous realizations of erbium-based telecom memories due to the non-compatible level structure.

One downside of our device is that the retrieved photon is still at 606 nm and would require yet another stage of frequency conversion to get back to the telecom wavelength, which would reduce the overall efficiency and increase greatly the possible $\mu_t$. However, for some quantum repeater architectures [7], it would not be necessary to convert back the stored photon. Entanglement swapping operations that extend entanglement between neighbouring links in a quantum repeater can be done locally [64], eliminating the need to convert back to telecom.

Previous experiments have shown that the process of nonlinear frequency conversion [49, 52, 65] and the AFC scheme [19, 23, 24] preserve quantum superpositions. Our device could therefore be used to convert and store time-bin qubits. The high signal to noise ratio obtained in our experiment should allow for the overall fidelity to be in the quantum regime. However, our device is not directly compatible with polarization qubits as only one polarization (vertical) is guided. The memory alone has been shown to store arbitrary polarizations [26], so a device that can convert arbitrary polarizations is needed to perform conversion and storage of polarization qubits. This could be realized with two waveguide set-ups, one converting the vertical component and one to convert the horizontal [43].

6. Conclusion

To conclude, we have demonstrated the storage of up-converted single-photon-level telecom light in a Pr$^{3+}$:Y$_2$SiO$_5$ crystal. We obtain an overall efficiency of $\eta_{tot} = 1.9 \pm 0.2\%$ for a storage time of 1.6 $\mu$s. Storage times of up to 10 $\mu$s were also realized. This is the first demonstration of
single-photon-level light storage interfaced with frequency up-conversion. Due to the fact that the echo is emitted at a predetermined time, and that the memory is narrowband relative to the broadband noisy conversion process, the signal to noise ratio of the retrieved light is two orders of magnitude superior to the input. With this in mind, we view our memory also as a noiseless converter of telecom light to the visible. Finally, our telecom conversion and storage device is in principle compatible with spin-wave storage protocols, a feature absent in previous realizations.

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